NSN 5961-01-300-8532

Diode Semiconductor Device - Page 1 of 1



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Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
D0-5
Mounting Method:
Threaded stud
Thready Qty Per Inch (tpi):
28
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1200.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
70.00 amperes forward current, average
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0